



Analytical Characterization of Common-mode Voltage in A Three-level ANPC Inverter

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Three-level ANPC Realization

- To have comparable travel time as petrol-driven vehicles, extreme fast charging is promoted. This requires at least 800 V DC-link voltage, which also increase the efficiency.
- □ Three-level is preferred for the lower cost of devices with lower voltage blocking capability, especially wide bandgap devices like GaN HEMTs.



Three-level ANPC Common-mode Voltage

- Since higher battery voltage directly increase the CMV, combined with higher switching speed, CM current is also larger, causing potentially bigger mechanical damage to the motor.
- □ By properly assigning the space vector combination, the CMV can be reduced even more.



Double Fourier Integral Analysis

- Double Fourier integral analysis can provide analytical solutions to identify harmonic components of the PWM signal.
- Functions x(t) and y(t) are the time variation of high-frequency carrier waveform and lowfrequency modulation waveform.

 $x(t) = \omega_s t + \theta_s$ $y(t) = \omega_0 t + \theta_0$

Switching function:

$$f(x,y) = \frac{A_{00}}{2} + \sum_{n=1}^{\infty} \left\{ A_{0n} \cos\left(n\left(\omega_0 t + \theta_0\right)\right) + B_{0n} \sin\left(n\left(\omega_0 t + \theta_0\right)\right) \right\} + \sum_{m=1}^{\infty} \left\{ A_{m0} \cos\left(m\left(\omega_s t + \theta_s\right)\right) + B_{m0} \sin\left(m\left(\omega_s t + \theta_s\right)\right) \right\}$$

$$+\sum_{m=1}^{\infty}\sum_{n=-\infty}^{\infty}\left\{A_{mn}\cos\left(m\left(\omega_{s}t+\theta_{s}\right)+n\left(\omega_{0}t+\theta_{0}\right)\right)+B_{mn}\sin\left(m\left(\omega_{s}t+\theta_{s}\right)+n\left(\omega_{0}t+\theta_{0}\right)\right)\right\}$$

$$n \neq 0$$



Continuous SVM



Three-level DFI

- There are 8 sections for each fundamental cycle. Especially, in sections 1, 2, 5, and 6, there are three integration areas. In sections 3, 4, 7, and 8, there is only one.
- □ The carrier harmonics and sideband components of the CMV can be calculated and compared to the simulation at f0=100 Hz, fs=10 kHz, 200V DC bus voltage.





DFI Bounds of Other 3L Modulations

- NTSVM is nearest three vector modulation. It uses three nearby vectors to compose the reference. RCMVM is reduced common-mode voltage modulation. It always uses low CMV vectors instead.
- □ By deriving the switching function, the DFI bounds with different MI can be plotted as below.



Result Comparison

□ Analytical CMV spectrum and the simulation result are compared below.

- At given DC bus voltage of 800 V, MI=0.8, fs=10 kHz and f0=100 Hz, the result shows very accurate agreement. (left and middle)
- □ This result is then compared to preliminary experiment test. (right)



Frequency/Hz

200

Test Platform

- Currently, we have built an 800 V, 75 kVA three-level all GaN inverter, with a power density of 25 kVA/L. Tests are conducting to gradually reach full power.
- □ More tests are on the way to prove the accuracy of our analytical calculation.



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